

Supplementary Information

Hybrid niobium-based oxide with bio-based porous carbon as efficient electrocatalyst in photovoltaics: A general strategy for understanding catalytic mechanism

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Details for the preparation of BPC, ZnNb₂O₆, and ZnNb₂O₆/BPC

Niobium chloride (NbCl₅, 0.287 g) and zinc nitrate nonahydrate (Zn(NO₃)₂·9H₂O, 0.516 g) was added to 20 mL deionized water and stirred until the metal salts was completely dissolved. 10 mL hydrazine hydrate was slowly added to the solution and stirred for 30 min. The obtained solution was transferred into a Teflon-lined stainless steel autoclave (200 mL). Subsequently, the autoclave was subjected to hydrothermal treatment at 120 °C for 12 h in an oven and was then cooled naturally. The hydrothermal precursor was processed by centrifuging with alcohol and deionized water and dried in an oven at 80 °C for 12 h, then the white powder was achieved. Finally, the dried product was annealed in a tubular furnace for 2 h under nitrogen flow at 800 °C, which resulted in the expected niobium-based oxide ZnNb₂O₆.

Aloe peel was used as raw material to prepare bio-based porous carbon (BPC). The aloe peel was dried at 105 °C and crushed into powder. The powder was added into 20 mL deionized water and stirred for 4h, then transferred into the autoclave to proceed a hydrothermal carbonization process at 120 °C for 12 h. The obtained black precipitate was dipped into 1 mol/L KOH, then stirred thoroughly to perform a chemical activation process. The mixture was dried at 90 °C and then sintered at 800 °C under an N₂ atmosphere for 2 h in a tubular furnace. Subsequently, the obtained black product was repeatedly washed by 1 mol/L HCl, deionized water and absolute ethanol until the pH value of solution was neutral, and dried to finally achieve the target material BPC. More

details on this type of bio-based carbon can be found in our previous literatures.¹⁻³

In terms of the preparation of ZnNb₂O₆/BPC (a molar ratio of 1: 4) nanohybrid, the two metal salts (NbCl₅ 0.287 g and Zn(NO₃)₂·9H₂O, 0.516 g) and BPC (0.048 g) were dispersed in 20 mL ethyl alcohol, respectively, and stirred for 4 h. Then the mixed solution was conducted hydrothermal process at 120 °C for 12 h to obtaining a gray sediment. The colloidal product was dried at 80 °C for 12 h. Finally, the target nanohybrid ZnNb₂O₆/BPC would be obtained after a 800 °C annealing process for 2 h.

X-ray diffraction peak assignments of the catalytic materials

Chemical composition, crystal structures, space groups, JCPDS Card number and lattice parameters of the ZnNb₂O₆ were summarized in Table S1.

Table S1 Details of the XRD patterns of ZnNb₂O₆.

Chemical formula	Crystal structures	JCPDS Card ^a	a (nm)	b(nm)	c(nm)
ZnNb ₂ O ₆	Orthorhombic	PDF#37-1371	5.031	14.187	5.723

^a PDF-2 database.

The diffraction peaks at 24.407°, 25.107°, 30.251°, 31.226°, 35.670°, 36.100°, 38.016°, 40.547°, 41.068°, 43.670°, 48.103°, 49.989°, 51.626°, 53.411°, 60.707°, 62.887°, 64.306°, 68.055° can be indexed to the (031), (040), (131), (002), (200), (102), (060), (230), (132), (202), (062), (033), (260), (162), (331), (191), (233), (104) reflection of the ZnNb₂O₆ crystalline structure (PDF#37-1371), respectively.

Tafel polarization

Tafel polarization is shown in Figure S1 and Equation S1-S10, the Tafel curve can be divided into three zones.^{4,5} The part at low potential is attributed to the polarization zone ($|U| < 116$ mV), in which the over potential (V) reveals a linear function of current density (J). The slope of the cross point of polarization and curve is the charge resistance (R_{ct}), which is inversely proportional to the exchange current density (J_0) and can be regarded as a crucial indicator to evaluate the electrochemical reaction activity, based on the Equation S5. The part at the middle potential is attributed to the Tafel zone, in which the potential (V) is a linear function of the logarithmic current density ($\lg J$) according to Equation S2. The curve at high potential ascribes to the diffusion zone, which is on account of the redox couple transmission.

Based on the Tafel zone and diffusion zone, the exchange current density (J_0) and the limiting diffusion current density (J_{lim}) can be obtained, which are closely related to the catalytic activity of electrocatalyst. Based on Equation S2, the Tafel zone J_0 can be acquired through extending the line to the potential as zero and the current density (J) obtained there. In Tafel zone, the intersection of the equilibrium potential line and the cathodic can be considered as the J_0 . The steeper curve means the higher J_0 value, which also indicates a better catalytic activity. In terms of the diffusion zone, J_{lim} depends on the diffusion capability of redox couple and the counter electrode catalyst. The J_{lim} can be obtained through the intersection of the cathodic branch with the Y axis. A higher J_{lim} means a larger diffusion coefficient at the same potential and higher diffusion velocity of

redox couple in the electrolyte. Seen from the Equation S2, S5 and S6, it can be found that the J_0 is inversely proportional to R_{ct} whereas J_{lim} is proportional to D . More detailed on the Tafel polarization, please consult our previous papers.^{4, 6-8}

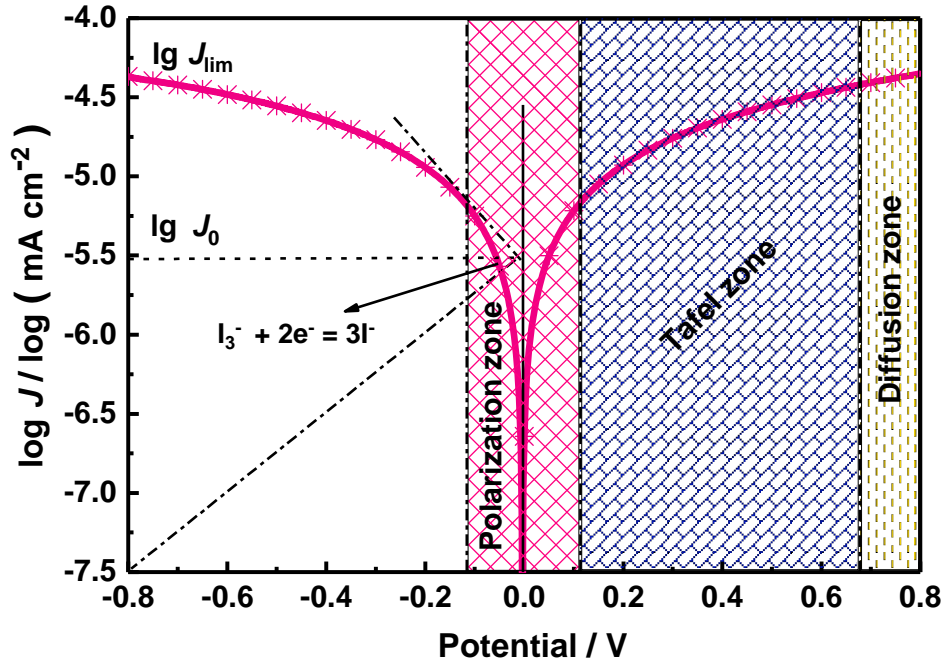


Figure S1 Annotation of Tafel curves.

$$V = a + b \lg J \quad (\text{Equation-S1})$$

$$V = \frac{2.3RT(\lg J - \lg J_0)}{\alpha nF} \quad (\text{Equation-S2})$$

$$a = -\frac{2.3RT}{\alpha nF} \lg J_0 \quad (\text{Equation-S3})$$

$$b = \frac{2.3RT}{\alpha nF} \quad (\text{Equation-S4})$$

$$J_0 = \frac{RT}{nFR_{ct}} \quad (\text{Equation-S5})$$

$$D = \frac{l}{2nFC} J_{lim} \quad (\text{Equation-S6})$$

The Nernst impedance describes the diffusion of the triiodide in the electrolyte, and can be expressed as follows:

$$Z_N = \frac{W}{\sqrt{i\omega}} \tanh\left(\sqrt{\frac{i\omega}{K_N}}\right) \quad (\text{Equation-S7})$$

$$W = \frac{kT}{n^2 e^2 C A \sqrt{D}} \quad (\text{Equation-S8})$$

$$J_{lim} = \frac{2neDCN_A}{l} \quad (\text{Equation-S9})$$

$$K_N = D/\delta^2 \quad (\text{Equation-S10})$$

where a and b are the constants, V is the overpotential, J is the polarization current density, R is the gas constant, T is the temperature, D is the diffusion coefficient of the triiodide, F is the Faraday constant, C is the triiodide concentration, n is the number of electrons exchanged in the reaction at the electrolyte-electrode interface, δ is the thickness of the diffusion layer, e is the elementary charge, k is the Boltzmann constant, A is the electrode active area, l is the distance between the electrodes (the spacer thickness), α is the distribution coefficient or symmetrical coefficient, N_A is the Avogadro constant, R_{ct} is the charge-transfer resistance, Z_N is the Nernst diffusion impedance, W is the Warburg parameter, J_0 is the exchange current density, and J_{lim} is the limiting diffusion current density.

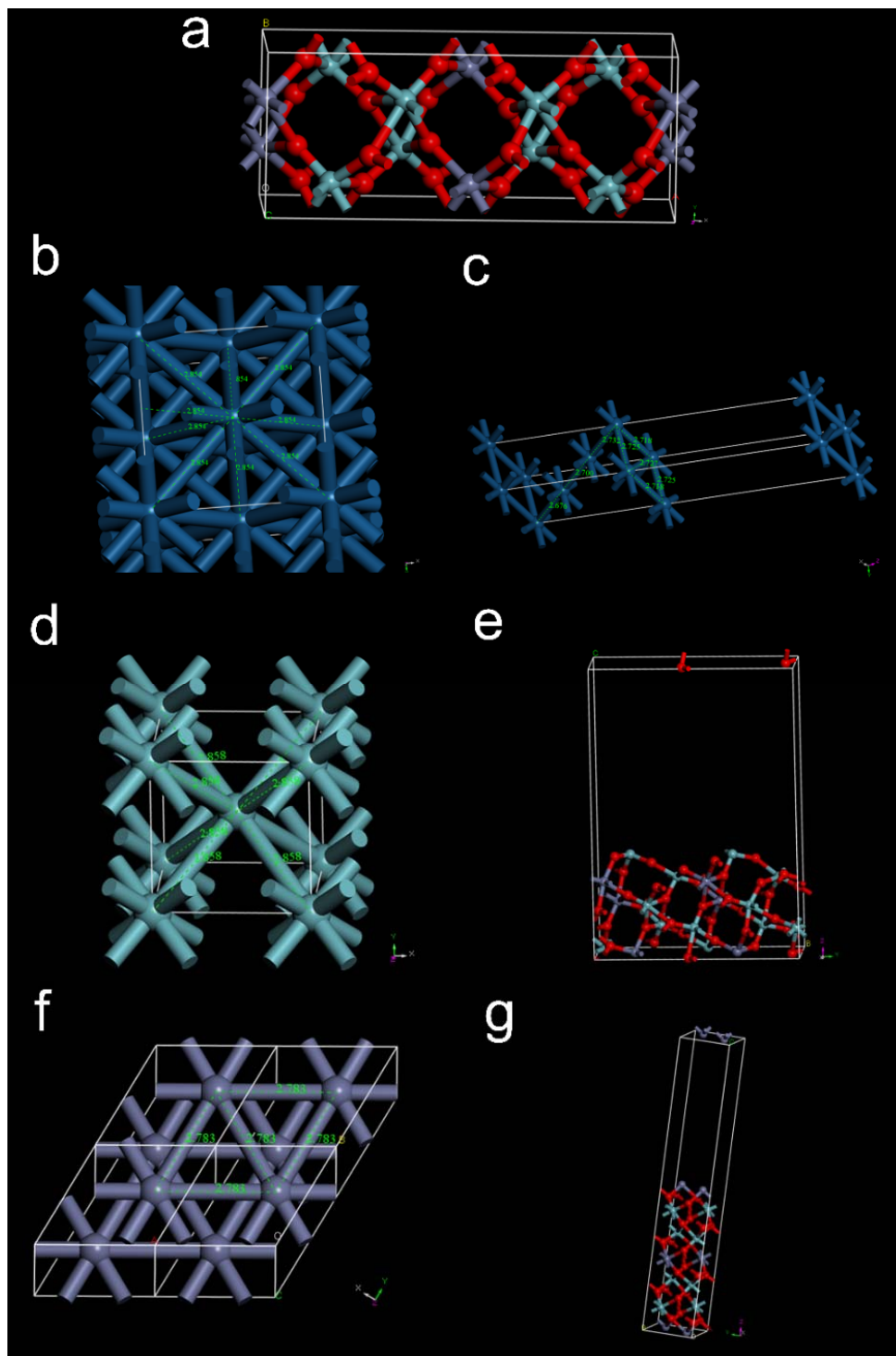


Figure S2 Geometric models (a) ZnNb_2O_6 of the *Pbcn* phase, (b) bulk Pt, (c) (111) surface of Pt, (d) bulk Nb, (e) (110) surface of ZnNb_2O_6 , (f) bulk Zn and (g) (100) surface of ZnNb_2O_6 .

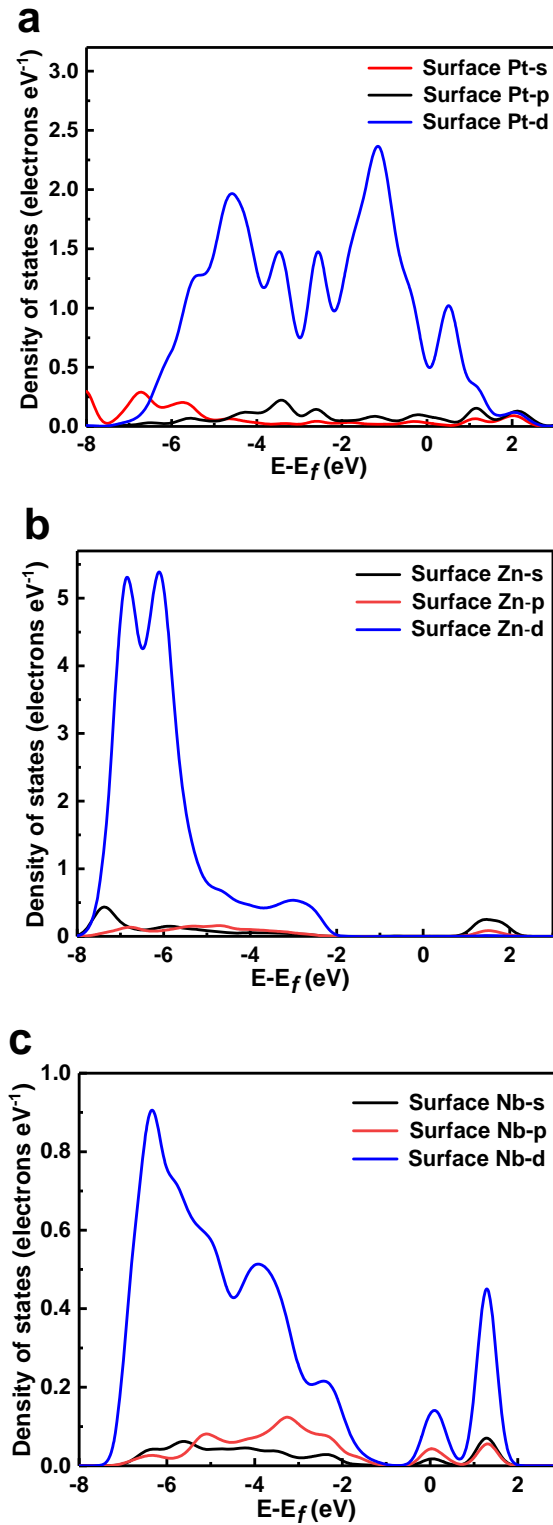


Figure S3 Projected density of states of (a) Pt atom in (111) surface of Pt, (b) Zn atom in (100) surface of $ZnNb_2O_6$, (c) Nb atom in (110) surface of $ZnNb_2O_6$.

Table S2 Photovoltaic parameters of DSSCs using transition metal compounds/carbon nanohybrid CEs. (AM 1.5, 100 mW cm⁻²).

Transition metal compounds/Carbon nanohybrids									
CEs	J _{sc} (mA cm ⁻²)	V _{oc} (mV)	FF	PCE (%)	Area (cm ²)	Dye	Electrolyte	Year	Ref.
Pt	12.48	730	0.65	6.40	0.20	Z907	I ⁻ /I ₃ ⁻	2009	9
TiO ₂ /Carbon	12.53	700	0.57	5.50	0.24				
Pt	12.83	735	0.60	5.68	0.25	N719	I ⁻ /I ₃ ⁻	2010	10
TiN	9.28	660	0.35	2.12					
CNTs	8.55	705	0.52	3.53					
TiN/CNTs	12.74	750	0.57	5.41					
Pt	13.71	780	0.71	7.55	0.16	N719	I ⁻ /I ₃ ⁻	2011	11
WO ₂	12.69	807	0.65	6.69					
MC	14.54	799	0.60	7.01					
WO ₂ /MC	13.55	808	0.71	7.76					
WC	41.01	650	0.56	5.10	0.16	N719	T ₂ /T ⁻	2011	12
WC/MC	14.45	650	0.57	5.34					
Pt	15.23	807	0.64	7.89	0.16	N719	I ⁻ /I ₃ ⁻	2011	13
MoC/MC	15.50	787	0.68	8.34					
WC/MC	14.59	804	0.70	8.18					
CoS/MWCNTs	15.96	720	0.64	6.96	0.283	N719	I ⁻ /I ₃ ⁻	2011	14
MoC/MC	15.50	787	0.68	8.34	0.16	N719	I ⁻ /I ₃ ⁻	2011	13
WC/MC	14.59	804	0.70	8.18					
Mo ₂ C/P25/CD	15.25	796	0.67	8.14					
WC/P25/CD	14.93	787	0.68	8.34					
Pt	10.12	765	0.6508	5.03	1.00	N719	I ⁻ /I ₃ ⁻	2011	15
TiN/NG	12.34	728	0.6433	5.78					
Pt	14.08	783	0.68	7.50	0.16	N719	I ⁻ /I ₃ ⁻	2012	16
VC/MC	13.11	808	0.72	7.63					
Pt	15.00	808	0.66	8.00	0.25	N719	I ⁻ /I ₃ ⁻	2012	17
TiO ₂ /MC	15.20	800	0.55	6.69					

TiN/MC	15.30	820	0.67	8.41					
Pt	15.44	652	0.33	3.32					
TiN/MC	14.36	697	0.67	6.71			T ₂ /T ⁻		
MC	14.54	800	0.60	7.01	0.16	N719	Γ/I ₃ ⁻	2012	18
Ni ₃ P ₄ /C	13.85	780	0.69	7.54					
Ni ₃ P ₄	13.84	770	0.54	5.71					
MoP	12.79	760	0.51	4.92					
MC	12.88	630	0.54	4.40	0.16	N719	T ₂ /T ⁻		
Ni ₃ P ₄ /C	11.81	630	0.64	4.75					
Ni ₃ P ₄	11.40	630	0.54	3.87					
Pt	13.33	782	0.63	6.59	1.00	N719	Γ/I ₃ ⁻	2012	19
C _b	12.80	760	0.61	5.93					
TiN	10.06	741	0.48	3.59					
TiN/C _b	14.29	791	0.70	7.92					
Pt	13.12	744	0.62	6.08	0.20	N719	Γ/I ₃ ⁻	2012	20
graphene	12.88	701	0.52	4.70					
Ni ₁₂ P ₅	12.24	727	0.44	3.94					
graphene/Ni ₁₂ P ₅	12.86	727	0.61	5.70					
Pt	15.86	740	0.63	7.35	0.20	N719	Γ/I ₃ ⁻	2012	21
MoN	13.71	670	0.61	5.57					
MoO ₂	12.52	515	0.43	2.79					
MoO ₂ /CNTs	13.67	725	0.44	4.34					
MoN/CNTs	14.40	735	0.64	6.74					
Pt	13.24	740	0.66	6.41	0.28	N719	Γ/I ₃ ⁻	2012	22
MoS ₂	11.25	720	0.61	4.99					
MWCNTs	9.11	650	0.58	3.53					
MoS ₂ /MWCNTs	13.69	730	0.65	6.45					
Pt	12.43	750	0.67	6.23	0.20	N719	Γ/I ₃ ⁻	2012	23
MoS ₂ /graphene	12.41	710	0.68	5.98					
Pt	12.47	730	0.71	6.48	0.25	N3	Γ/I ₃ ⁻	2012	24
Carbon/SnO ₂ /TiO ₂	12.98	740	0.64	6.15					
Pristine graphene	11.0	670	0.171	1.27	----	N719	Γ/I ₃ ⁻	2012	25
CoS/graphene	12.8	720	0.364	3.42					

Pt	13.23	760	0.75	7.54	0.20	N719	I/I_3^-	2012	26
WS ₂	11.72	720	0.63	5.32					
MWCNT	10.77	660	0.61	4.34					
WS ₂ /MWCNT	13.63	750	0.72	7.36					
Hf ₇ O ₈ N ₄ /HfO ₂ /C	14.13	800	0.70	7.85	0.16	N719	I/I_3^-	2013	27
HfO ₂ /C	12.96	770	0.67	6.71					
HfO ₂	12.63	730	0.40	3.73					
Pt	6.47	580	0.44	1.87	0.25	N719	Co ²⁺ /Co ³⁺	2013	28
Ag nanowire	5.32	540	0.36	1.09					
Ag nanowire/GNP	6.45	550	0.52	1.61					
Pt	13.73	835	0.69	7.91	0.25	FNE29	Co ²⁺ /Co ³⁺	2013	29
TaON	11.35	773	0.29	2.54					
graphene	12.33	814	0.46	4.62					
graphene/TaON	13.38	829	0.69	7.65					
Pt	15.75	739	0.70	8.15	0.25	N719	I/I_3^-	2013	30
NiS ₂	14.42	738	0.66	7.02					
graphene	10.98	716	0.40	3.14					
RGO/NiS ₂	16.55	749	0.69	8.55					
Pt	13.38	828	0.685	7.59	0.25	FNE29	Co ²⁺ /Co ³⁺	2013	31
Ta ₃ N ₅	11.69	783	0.316	2.89					
graphene	12.41	819	0.448	4.55					
graphene/Ta ₃ N ₅	13.53	837	0.693	7.85					
Pt (FTO)	9.92	730	0.69	5.00	----	N719	I/I_3^-	2013	32
graphene(SiO ₂)	8.68	691	0.3234	1.94					
NiS/graphene(SiO ₂)	10.31	724	0.7036	5.25					
NiS(FTO)	9.42	707	0.6288	4.19					
CoS/graphene(SiO ₂)	10.03	725	0.6928	5.04					
CoS(FTO)	9.01	708	0.6161	3.93					
Pt	13.98	730	0.66	6.74	0.20	N719	I/I_3^-	2013	33
MoS ₂	11.66	730	0.63	5.36					
MoS ₂ /C	15.07	750	0.68	7.69					

Pt	13.98	720	0.64	6.40	0.12	N719	Γ/I_3^-	2013	34
Graphitic Carbon(GC)	12.71	710	0.53	4.75					
Fe ₃ C/GC	13.77	700	0.63	6.04					
Pt	12.95	750	0.66	6.41	0.20	N719	Γ/I_3^-	2013	35
Graphene flake	10.96	690	0.48	3.63					
MoS ₂	10.56	670	0.58	4.10					
MoS ₂ /graphene	13.27	750	0.61	6.07					
Pt	13.12	763	0.62	6.24	0.28	N719	Γ/I_3^-	2013	36
MoS ₂	12.92	701	0.46	4.15					
Graphene nanosheets	11.99	754	0.30	2.68					
MoS ₂ /graphene	12.79	773	0.59	5.81					
Pt	12.46	751	0.68	6.36	0.28	N719 Ti foil	Γ/I_3^-	2013	37
MWCNT	7.83	591	0.33	1.53					
NiS	13.25	752	0.71	7.07					
NiS/MWCNT	14.18	753	0.74	7.90					
Pt	12.35	750	0.69	6.39	0.28	N719 Ti foil	Γ/I_3^-	2013	38
MWCNT	8.25	376	0.41	1.27					
CoS	13.88	750	0.71	7.38					
CoS/MWCNT	14.69	751	0.73	8.05					
Pt	13.23	740	0.67	6.56	0.20	N719	Γ/I_3^-	2013	39
WS ₂	11.28	720	0.59	4.79					
MWCNT	10.77	660	0.61	4.34					
5wt.% MWCNT/WS ₂	13.51	730	0.65	6.41					
Pt	13.80	540	0.41	3.06	0.16	Quantum DSSC	polysulfide electrolyte	2013	40
MWCNT	13.40	510	0.35	2.39					
CZTSe	16.36	530	0.44	3.06					
MWCNT/CZTSe	17.04	530	0.51	4.60					
Pt	15.18	710	0.68	7.32	0.16	N719	Γ/I_3^-	2013	41

MC	14.45	770	0.64	7.19					
TaO/MC	14.97	800	0.68	8.09					
TaC/MC	14.51	800	0.68	7.93					
Pt	13.99	750	0.68	7.19	0.16	N719	Γ/I_3^-	2013	27
HfO ₂	12.63	730	0.40	3.73					
HfO ₂ /C	12.96	770	0.67	6.71					
Hf ₇ O ₈ N ₄ /HfO ₂ /C	14.13	800	0.70	7.85					
Rosin carbon	14.41	795	0.61	7.00	0.16	N719	Γ/I_3^-	2013	42
Carbon/Fe ₃ O ₄	16.01	750	0.68	8.11					
HfO ₂ /MC	14.36	800	0.67	7.75	0.16	N719	Γ/I_3^-	2014	43
	10.45	590	0.60	3.69			T ₂ /T ⁻		
SnS ₂ /C	17.47	745	0.619	8.06	0.16	N719	Γ/I_3^-	2014	44
Cu/PACF	8.49	720	0.52	3.20	0.16	N719	Γ/I_3^-	2014	45
Cu/PACF/CNF	11.12	750	0.54	4.36					
WC/C	15.35	760	0.67	7.77	0.25	N719	Γ/I_3^-	2014	46
	13.96	630	0.66	5.85			T ₂ /T ⁻		
Bi ₂ S ₃ /RGO	12.20	750	0.60	5.5	0.25	N719	Γ/I_3^-	2014	47
CNTs/MoS ₂	14.93	650	0.47	4.51	0.25	N719	Γ/I_3^-	2014	48
CNTs/MoS ₂ /carbon	16.44	790	0.57	7.23					
CoS	11.78	670	0.61	4.79	3.75	N719	Γ/I_3^-	2014	49
CoS/FGN	12.91	670	0.64	5.54					
MWCNT	14.83	700	0.56	5.81	0.25	N3	Γ/I_3^-	2014	50
TiO ₂ /MWCNT	15.71	720	0.68	7.69					
Pt	16.25	635	0.66	6.84	0.2	N3	Γ/I_3^-	2014	51
Mn ₃ O ₄ /RGO	15.20	635	0.61	5.90					
Pt	16.00	710	0.60	6.82	0.25	N719	Γ/I_3^-	2014	52
NiSe ₂ /RGO	15.82	730	0.61	6.94					
TiC/SiC/C	11.13	782	0.654	5.7	----	N719	Γ/I_3^-	2014	53
Pt	14.77	751	0.62	6.92	0.25	N719	Γ/I_3^-	2014	54
CuInS ₂ /RGO	16.61	782	0.58	6.96					
Bi ₂ S ₃	15.34	690	0.438	4.78	----	N719	Γ/I_3^-	2014	55
Bi ₂ S ₃ /RGO (9wt%)	15.33	740	0.609	6.91					
ZnO/GNs	21.70	765	0.671	8.12	----	N719	Γ/I_3^-	2015	56
CoNi ₂ S ₄ /carbon fibers	15.3	680	0.677	7.03	----	N719	Γ/I_3^-	2015	57

Pt	17.10	780	0.62	8.16	----	N719	Γ/I_3^-	2015	58
RuO ₂ /G	16.13	766	0.67	8.32	----	N719	Γ/I_3^-	2015	59
CoS ₂ /RGO	12.87	670	0.63	5.43	----	Z907	Γ/I_3^-	2015	59
CoS/GR	15.07	748	0.56	6.31	0.20	N719	Γ/I_3^-	2015	60
CdS/RGO	14.81	760	0.656	7.39	0.25	N719	Γ/I_3^-	2015	61
SnO ₂ /RGO	14.25	720	0.66	6.78	----	N719	Γ/I_3^-	2015	62
TiO ₂ /C	4.0	710	0.622	1.9	1	N719	Γ/I_3^-	2015	63
Cu-Ni/GR	13.35	660	0.623	5.46	0.16	N719	Γ/I_3^-	2015	64
SnS ₂ /RGO	14.80	718	0.67	7.12	0.25	N719	Γ/I_3^-	2015	65
CoTe/RGO	17.41	770	0.685	9.18	----	N719	Γ/I_3^-	2015	66
MoS ₂ /MWCNT	16.71	737	0.608	7.50	0.15	N719	Γ/I_3^-	2015	67
MoS ₂ /G	15.64	685	0.67	7.18	----	N719	Γ/I_3^-	2015	68
PtO/MWCNTs	17.93	763	0.633	8.67	0.25	N719	Γ/I_3^-	2015	69
AuNP/RGO	7.27	355.2	0.50	1.30	0.49	N719	Γ/I_3^-	2015	70
CoS/RGO _{0.2}	19.42	764	0.633	9.39	----	N719	Γ/I_3^-	2015	71
NiCo/CNFs	11.12	740	0.54	4.47	0.25	N719	Γ/I_3^-	2015	72
NiO/MWCNT	18.54	644	0.639	7.63	0.15	N719	Γ/I_3^-	2015	73
TiO _{2-x} /CNT	12.36	700	0.66	5.71	----	N719	Γ/I_3^-	2015	74
NiCo ₂ O ₄ /G	16.12	750	0.67	8.10	0.28	N719	Γ/I_3^-	2015	75
NiO/acetylene black	16.28	780	0.61	7.75	0.15	N719	Γ/I_3^-	2015	76
CoS/G	15.07	748	0.56	6.31	0.20	N719	Γ/I_3^-	2015	60
CoS/G	17.02	770	0.63	8.34	0.30	N719	Γ/I_3^-	2015	77
Ni ₃ S ₂ /C	20.75	750	0.62	9.64	----	N719	Γ/I_3^-	2015	78
Ni _{0.75} Cu _{0.25} /G	10.35	750	0.65	5.1	0.25	N719	Γ/I_3^-	2015	79
Ni _{0.6} Cu _{0.4} /G	10.03	720	0.39	2.87					
Cu _{0.75} Ni _{0.25} /G	7.44	518	0.32	1.24					
Fe ₂ O ₃	13.60	711	0.61	5.89	0.16	N719	Γ/I_3^-	2016	80
Fe ₂ O ₃ /GFs	15.05	728	0.68	7.45					
Pt	14.89	719	0.68	7.29					
g-C ₃ N ₄	8.8	540	0.41	1.95	0.2	N3	Γ/I_3^-	2016	81
MWCNT	12.6	640	0.53	4.27					
g-C ₃ N ₄ /MWCNT	14.2	720	0.62	6.34					
Pt	14.6	710	0.66	6.84					
CoS	17.028	766	0.651	8.49	0.12	N719	Γ/I_3^-	2016	82
CoS/rGO _{0.10}	18.903	767	0.677	9.82					

rGO	15.368	733	0.013	2.01					
Co/RGO	14.22	750	49.6	5.29	----	N719	Γ/I_3^-	2016	83
Pt _{0.1} Co _{0.9} /RGO	14.66	745	68.1	7.44					
Pt/RGO	14.79	730	65.4	7.06					
CoS/G	12.09	630	0.71	5.41	0.16	Z907	Γ/I_3^-	2016	84
CoS	10.93	610	0.61	4.07					
RGO	10.21	620	0.35	2.22					
Nb ₂ O ₅	12.27	683	0.59	4.95	0.16	N719	T_2/T^-	2016	85
	15.18	868	0.63	8.29			Co ²⁺ /Co ³⁺		
Nb ₂ O ₅ /C	13.39	689	0.66	6.11			T_2/T^-		
	15.68	861	0.73	9.86			Co ²⁺ /Co ³⁺		
MoS ₂ /G	16.1	660	0.67	7.1	0.16	N719	Γ/I_3^-	2016	86
TiO ₂ /C _a	15.83	705	0.55	6.04	----	N719	Γ/I_3^-	2016	87
Ni/GO	17.8	750	0.62	8.30	0.16	N719	Γ/I_3^-	2016	88
La _{0.65} Sr _{0.35} MnO ₃ /RGO	12.53	780	0.67	6.57	----	N719	Γ/I_3^-	2016	89
g-C ₃ N ₄ /CCB	13.21	688	0.56	5.09	0.2	N3	Γ/I_3^-	2016	90
Ni-Co/CNFs	9.78	730	0.64	4.57	0.2	N719	Γ/I_3^-	2016	91
10wt%CNFs-TiC	9.71	720	0.64	4.5	0.25	N719	Γ/I_3^-	2016	92
MnO ₂ +6wt% RGO	15.97	705	0.509	5.77	0.25	N719	Γ/I_3^-	2016	93
NiCo ₂ O ₄ /RGO	14.92	690	0.599	6.17	----	N719	Γ/I_3^-	2016	94
PbSe/RGO	15.24	570	0.65	6.5	0.25	N719	Γ/I_3^-	2016	95
PbSe	4.62	570	0.45	1.2					
ZnSe	6.14	540	0.43	1.44	---	N719	Γ/I_3^-	2016	96
ZnSe/RGO	15	780	0.57	6.61					
CoS ₂	4.11	530	0.53	1.18	0.25	N719	Γ/I_3^-	2016	97
CoS ₂ /RGO	15.2	770	0.55	6.49					
Bi ₂ Se ₃	7.02	550	0.46	1.86	0.25	N719	Γ/I_3^-	2016	98
Bi ₂ Se ₃ /RGO	16.36	750	0.57	7.09					
Pt	15.65	680	0.59	6.47					
rGO	4.35	695	0.2447	0.74	---	N719	Γ/I_3^-	2016	99
Co ₉ S ₈	14.74	669	0.5821	5.74					
Co ₉ S ₈ /rGO	15.24	703	0.6627	7.10					
Pt	15.68	693	0.6856	7.45					
MnO _x	2.99	700	0.45	0.77	---	N719	Γ/I_3^-	2016	100
CNT	6.12	750	0.42	2.40					
CNT/MnO _x	3.93	740	0.48	1.39					
CNT/MnO _x /CNT	4.67	780	0.55	2.01					
In ₂ O ₃	1.82	250	0.30	0.14	---	N719	Γ/I_3^-	2016	101

In ₂ O ₃ -MWCNTs	9.45	370	0.37	1.29					
ACs	15.01	730	0.60	6.57	0.15	N719	Γ/I ₃ ⁻	2016	102
Nano-Si@ACs	15.50	760	0.67	8.01					
Pt	15.20	740	0.64	7.20					
MoS ₂	8.15	610	0.21	1.04	0.2	N3	---	2016	103
MoS ₂ /AB	10.27	640	0.20	1.31					
MoS ₂ /VC	10.81	640	0.43	2.97					
MoS ₂ /CNT	12.43	620	0.4	3.08					
MoS ₂ /CNF	10.33	580	0.53	3.17					
MoS ₂ /RHA	10.95	600	0.32	2.10					
In _{2.77} S ₄ @Cc	17.34	750	0.67	8.71	0.16	N719	Γ/I ₃ ⁻	2016	104
In _{2.77} S ₄	15.06	680	0.47	4.81					
Cc	16.56	740	0.63	7.72					
Pt	19.19	760	0.60	8.75					
CNT/TiO ₂	15.96	770	0.57	7.00	0.25	N719	Γ/I ₃ ⁻	2016	105
TiO ₂	15.68	770	0.54	6.51					
In ₂ O ₃	4.83	320	0.38	0.59	1.5	N719	Γ/I ₃ ⁻	2016	106
In ₂ O ₃ -MWCNTs _(0.1%)	4.28	430	0.40	0.74					
In ₂ O ₃ -MWCNTs _(0.2%)	5.23	480	0.41	1.03					
In ₂ O ₃ -MWCNTs _(0.3%)	5.63	510	0.43	1.23					
In ₂ O ₃ -MWCNTs _(0.4%)	4.92	450	0.41	0.91					
In ₂ O ₃ -MWCNTs _(0.5%)	4.62	400	0.40	0.74					
Fe ₃ O ₄	11.26	511	0.31	2.1	0.25	N719	Γ/I ₃ ⁻	2016	107
Carbon Black	5.84	655	0.47	2.2					
Fe ₃ O ₄ -CB (1:1)	14.14	660	0.49	5.8					
Fe ₃ O ₄ -CB (1:2)	14.40	665	0.51	6.1					
Fe ₃ O ₄ -CB (2:1)	12.55	650	0.50	5.0					
Pt	9.33	675	0.52	4.1					
NiSe ₂ nanoparticles	13.96	750	0.62	6.49	---	N719	Γ/I ₃ ⁻	2016	108
NiSe ₂ +3 wt% graphene	14.86	750	0.62	6.91					
NiSe ₂ +6 wt% graphene	16.32	750	0.61	7.47					
NiSe ₂ +9 wt% graphene	14.67	760	0.64	7.14					
Pt	15.25	760	0.63	7.28					
Pt	13.0	720	0.69	6.47	0.25	---	Γ/I ₃ ⁻	2016	109
Sb ₂ Se ₃	11.3	640	0.43	3.08					
CNP	12.4	700	0.57	4.97					
Sb ₂ Se ₃ -CNP	12.7	730	0.68	6.26					
CoSe ₂ /C-NG	17.51	730	0.67	8.41	0.24	N719	Γ/I ₃ ⁻	2016	110
CoSe ₂ /C-NR	15.98	730	0.67	7.83					
CoSe ₂ /C-NCW	18.03	730	0.67	8.92					

Pt	16.43	740	0.67	8.25					
Ni _{0.85} Se	17.86	743	0.675	8.96 (Front)	0.11	N719	Γ/I_3^-	2016	111
	9.51	715	0.772	5.25 (Rear)					
Ni _{0.85} Se/RGO _{0.05}	18.66	751	0.666	9.75 (Front)					
	8.06	720	0.696	3.97 (Rear)					
Ni _{0.85} Se/RGO _{0.1}	19.94	751	0.652	9.75 (Front)					
	7.87	717	0.702	3.97 (Rear)					
Ni _{0.85} Se/RGO _{0.15}	18.13	765	0.641	8.89 (Front)					
	6.90	715	0.713	3.52 (Rear)					
Pt	16.51	746	0.662	8.15 (Front)					
	1.19	683	0.664	0.54 (Rear)					
NiS	17.08	680	0.52	6.04	0.16	N719	Γ/I_3^-	2016	112
NiS/Ca	15.56	720	0.61	6.83					
NiS/Cc	18.18	760	0.59	8.15					
Pt	16.03	750	0.69	8.29					
MoS ₂	6.76	640	0.50	2.18	---	---	Γ/I_3^-	2016	113
MoS ₂ /graphene	16.64	760	0.58	7.31					
graphene	18.92	770	0.46	6.72					
FeN	14.02	690	0.70	6.79	0.20	N719	Γ/I_3^-	2016	114
N-doped graphene	16.13	730	0.74	8.71					
FeN/N-doped graphene	18.83	740	0.78	10.86					
Pt	16.98	750	0.78	9.93					
MoS ₂	15.95	720	0.599	6.89	---	N719	Γ/I_3^-	2016	115
MoS ₂ /graphene	16.96	720	0.657	8.01					
Pt	16.86	730	0.6672	8.21					
RGO	9.32	720	0.4098	2.75	---	---	Γ/I_3^-	2016	116
Co ₃ O ₄	7.43	660	0.2447	1.20					
Co ₃ O ₄ @RGO	11.91	790	0.6154	5.79					
Pt	11.65	790	0.6693	6.16					
Pt	15.289	743	0.683	7.76	0.28	Z907	Γ/I_3^-	2016	117
Graphene	12.085	706	0.612	5.22					
NiS	12.836	717	0.651	5.99					
NiS/Gr	14.244	727	0.678	7.02					
NiS/Ag	14.909	735	0.654	7.17					
NiS/Gr-Ag	16.205	753	0.685	8.36					
NiS/AB(acetyleneblack)	14.01	720	0.67	6.75	0.2	N3	Γ/I_3^-	2016	118
NiS	12.71	680	0.69	5.96					
Pt	17.32	660	0.63	7.20					
NiSe-Ni ₃ Se ₂ /RGO-HD	16.31	750	0.64	7.83	---	N719	Γ/I_3^-	2016	119

NiSe/RGO-NP	13.80	750	0.60	6.21					
NiSe-Ni ₃ Se ₂ /RGO-NP	14.41	750	0.65	7.02					
NiSe-Ni ₃ Se ₂ /RGO-SD	14.03	750	0.64	6.73					
NiSe-Ni ₃ Se ₂ /RGO-HD-10h	15.48	760	0.63	7.41					
Pt	15.25	760	0.63	7.28					
Pt	16.45	780	0.48	6.08	---	N719	Γ/I_3^-	2017	120
MoSe ₂ /rGO	17.11	770	0.50	6.56					
Pt	14.83	740	0.65	7.15	0.28	N719	Γ/I_3^-	2017	121
MoS ₂	14.44	740	0.64	6.81					
CNTs	13.33	750	0.62	6.15					
MoS ₂ /CNTs	16.65	740	0.66	7.83					
Pt	18.34	716	0.5514	7.23					
MoS ₂ -graphene aerogel (MG)	17.24	714	0.6383	7.86	---	N719	Γ/I_3^-	2017	122
MoS ₂	13.64	780	0.2045	2.20					
Pt	12.79	720	0.675	6.22	0.25	(Bu ₄ N) ₂ [Ru (Hdcbpy) ₂ (NCS) ₂]	Γ/I_3^-	2017	123
MoS ₂ /GP	13.34	696	0.698	6.48					
GP	9.61	667	0.395	2.53					
Pt	15.58	784	0.68	8.27					
CNFs	12.58	777	0.62	6.11					
MnO ₂ /CNFs-1	14.43	786	0.65	7.42	---	N719	Γ/I_3^-	2017	124
MnO ₂ /CNFs-2	15.29	782	0.68	8.09					
MnO ₂ /CNFs-3	16.15	783	0.70	8.86					
MnO ₂ /CNFs-4	15.18	779	0.66	7.77					
NiS	14.007	692	0.721	6.98					
NiS-G0.2	14.398	698	0.696	6.99					
NiS-G0.4	14.586	712	0.727	7.54					
NiS-G0.6	15.814	715	0.724	8.18	0.25	N719	Γ/I_3^-	2017	125
NiS-G0.8	15.600	704	0.691	7.59					
Pt	15.606	711	0.726	8.05					
Graphene	12.461	703	0.344	3.02					
CoSe _{0.85}	14.182	687	0.666	6.49					
CoSe _{0.85} -G25	14.218	691	0.695	6.83	0.25	N719	Γ/I_3^-	2017	126
CoSe _{0.85} -G50	14.342	711	0.722	7.36					
CoSe _{0.85} -G75	15.789	715	0.724	8.17					
CoSe _{0.85} -G90	15.581	703	0.694	7.60					
RGO	13.24	686	0.38	3.47					
CoS ₂	14.13	693	0.56	5.48	---	N719	Γ/I_3^-	2017	127
CoS ₂ /RGO	16.35	702	0.67	7.69					
Pt	15.51	706	0.67	7.38					

RGO	8.86	721	0.16	1.01	---	N719	F/I ₃ ⁻	2017	128
Co _{0.85} Se	14.51	706	0.52	5.34					
Co _{0.85} Se/RGO	16.01	706	0.69	7.81					
Pt	15.44	707	0.69	7.55					
Pt	14.52	740	0.76	8.12	0.25	---	F/I ₃ ⁻	2017	129
Ni ₂ P ₂ O ₇ -NiO/C5	2.41	650	0.08	0.13					
Ni ₂ P ₂ O ₇ -Ni ₃ P-Ni/C5	6.16	650	0.16	0.64					
Ni ₂ P ₂ O ₇ -Ni ₁₂ P ₅ -Ni ₈ P ₃ /C5	12.34	720	0.61	5.44					
Ni ₂ P/C2.5	13.53	750	0.76	7.81					
Ni ₂ P/C5	14.78	770	0.77	8.82					
Ni ₂ P/C10	14.89	780	0.83	9.57					
Ni ₂ P/C20	13.95	770	0.78	8.38					
Ni ₂ P/C40	13.42	770	0.76	7.91					
Ni ₁₂ P ₅ /C10	13.88	760	0.75	7.94					
Pt	15.77	700	0.65	7.19	0.16	N719	F/I ₃ ⁻	2018	130
Ta/Co-N-C	18.11	650	0.68	7.96					
Co-N-C	13.02	720	0.67	6.25					

Abbreviation used:

FTO	fluorine-doped tin oxide
TMCs	transition metal compounds
C _a	activated carbon
C _b	carbon black
C _c	conductive carbon
C _f	carbon fiber
CD	carbon dye
C _p	discarded toner of a printer
C60	fullerene
MC	mesoporous carbon
CNTs	carbon nanotubes
CNP	carbon nanoparticle
CNFs	carbon nanofires
NG	nanograin
NR	nanorock
NP	nanoparticle
AB	acetylene black
VC	vulcan carbon
RHA	rice husk ash
NCW	nanoclimbing-wall
GNP	graphene nanoplatelets
GO	graphene oxide

RGO	reduced graphene oxide
SWCNTs	single-wall CNTs
MWCNTs	multi-wall CNTs
GNP	graphene nanoplatelets
NG	N-doped rGO

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